







Low Voltage SPST 0.8Ω Analog Switch

Features

- → CMOS Technology for Bus and Analog Applications
- → Low On-Resistance: 0.8Ω at 3.0V
- → Wide V_{CC} Range: 1.65V to 5.5V
- → Rail-to-Rail Signal Range
- → Control Input Overvoltage Tolerance: 5.5V
- → Fast Transition Speed: 2ns at 5.0V
- → High Bandwidth: 200MHz
- → Extended Industrial Temperature Range: -40°C to 85°C
- → I/O pins Has Power-off Protection Function
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → Packaging (Pb-free & Green):
 - 5-pin SOT23
 - 5-pin SC70

Applications

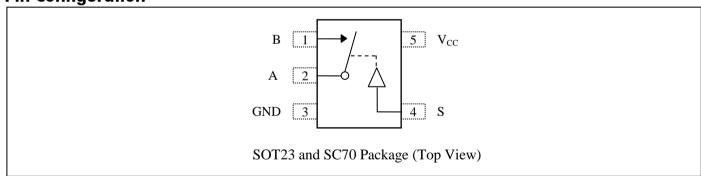
- → Cell Phones
- → PDAs
- → Portable Instrumentation
- → Battery powered Communications
- → Computer Peripherals

Description

The PI5A3166 is a high-bandwidth, fast single-pole single-throw (SPST) CMOS switch. It can be used as an analog switch or as a low-delay bus switch. The device features ultra low RON of 0.8Ω typical at 3.0V VCC and will operate over the wide VCC range of 1.65V to 5.5V.

The PI5A3166 features very low quiescent current even when the control voltage is lower than the VCC supply. This feature services the mobile handset applications very well by allowing direct interface with baseband processor general purpose I/Os. The control input, S, is independent of supply voltage.

Pin Configuration



Pin Description

Pin No	Pin Name	Description
1	В	Data Port
2	A	Common Output/Data Port
3	GND	Ground
4	S	Logic Control
5	VCC	Positive Power Supply

Logic Function Table

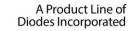
Logic Input(S)	Function(A to B)
0	OFF
1	ON

Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.







Maximum Ratings

	Storage Temperature	
ı	Ambient Temperature with Power Applied	40°C to +85°C
	Supply Voltage V _{CC}	0.5V to +7.0V
	DC Switch Voltage V _S	0.5V to +7.0V
	DC Input Voltage V _{IN}	0.5V to +7.0V
	DC Output Current V _{OUT}	128mA
	DC V_{CC} or Ground Current I_{CC} / I_{GND}	±100mA
ı	Junction Temperature under Bias (TJ)	150°C
ı	Junction Lead Temperature (TL)	
	(Soldering, 10 seconds)	260°C
	ESD (HBM)	4KV
ı	Power Dissipation (PD) @ +85°C	SOT23 250mW
ı	-	SC70 200mW

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V_{CC}	Operating Voltage	-	1.65	-	5.5	V
V _{IN}	DC Input Voltage	-	0	-	V_{CC}	V
V _S	Switch Input Voltage	-	0	-	5.5	V
V _{OUT}	Output Voltage	-	0	-	V_{CC}	V
T_A	Operating Temperature	-	-40	25	85	°C
4 4	t t Input Disc and Fall Time	Control Input $VCC = 2.7V$ to $3.6V$	0	-	10	ns/V
t_r, t_f	Input Rise and Fall Time	Control Input $VCC = 4.5V$ to $5.5V$	0	-	5	ns/V

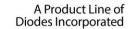
Note: Control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics

 $(T_A = -40$ °C to 85 °C, unless otherwise noted.)

Parameter	Description	Test Conditions	Supply Voltage	Min	Тур	Max	Units
V _{IAR}	Analog Input Signal Range	-	V _{CC}	0	-	VCC	V
		$I_A = 100 \text{mA}, V_B = 0 \text{V}$		-	0.7	1.1	
		$I_A = 100 \text{mA}, V_B = 2.4 \text{V}$	4.5V	-	0.6	1.0	
		$I_A = 100 \text{mA}, V_B = 4.5 \text{V}$		-	0.8	1.2	
	40	$I_A = 100 \text{mA}, V_B = 0 \text{V}$	2.01/	-	0.8	1.3	
R _{ON}	ON Resistance (1)	$I_A = 100 \text{mA}, V_B = 3.0 \text{V}$	3.0V	-	0.9	1.9	Ω
		$I_{A} = 100 \text{mA}, V_{B} = 0 \text{V}$	2.21/	-	1.0	1.5	
		$I_A = 100 \text{mA}, V_B = 2.3 \text{V}$	2.3V	-	1.2	1.8	
		$I_A = 100 \text{mA}, V_B = 0 \text{V}$	1 (FV	-	1.3	1.9	
		$I_A = 100 \text{mA}, V_B = 1.65 \text{V}$	1.65V	-	2.0	2.8	
	ON Resistance Flatness (2)	$I_A = 100 \text{mA}, V_B = 0 \text{V}, 2.4 \text{V}, 4.5 \text{V}$	4.5V	-	0.2	0.4	Ω
D		$I_A = 100 \text{mA}, V_B = 0 \text{V}, 1.5 \text{V}, 3.3 \text{V}$	3.3V	-	0.2	0.4	
R _{ONF}		$I_A = 100 \text{mA}, V_B = 0 \text{V}, 1.1 \text{V}, 2.5 \text{V}$	2.5V	-	0.4	0.6	
		$I_A = 100 \text{mA}, V_B = 0 \text{V}, 0.7 \text{V}, 1.8 \text{V}$	1.8V	-	1.0	1.4	
			$V_{CC} = 1.65V$	1	-	-	
	Input High Voltage		$V_{CC} = 2.3V$	1.2	-	-	
V_{IH}		Logic High Level	$V_{CC} = 3V$	1.3	-	-	V
			$V_{CC} = 4.2V$	1.5	-	-	
			$V_{\rm CC} = 5.5 V$	1.8	-	-	







			$V_{CC} = 1.65V$	-	-	0.4	
			$V_{CC} = 2.3V$	-	-	0.6	
$V_{_{\rm I\!L}}$	Input Low Voltage	Logic Low Level	$V_{CC} = 3V$	-	-	0.8	V
			$V_{CC} = 4.2V$	-	-	1	
			$V_{\rm CC} = 5.5 V$	-	-	1.2	
I _{OFF (B)}	Source Off Leakage Current	V _{CC} =5.5V, VA =1V, 4.5V VB =1V, 4.5V	$V_{CC} = 3V$	-20	-	+20	A
I _{NC(A, B)}	Channel On Leakage Current	-	$V_{CC} = 1.65 \text{ to}$ 5.5V	-40	-	+40	nA
I _{PWROFF}	Input Leakage Current for Power off	0≤V _A ≤5.5V 0≤V _B ≤5.5V	V _{CC} =0V	-5	-	5	μΑ
T	Quiescent Supply Current	All channels ON or OFF,	$V_{CC} = 3.6V$	-	0.002	0.1	۸
I_{CC}	Quiescent Supply Current	$V_B = V_{CC}$ or GND, $I_{OUT} = 0$	$V_{\rm CC} = 5.5 V$	-	0.002	0.1	μΑ

Notes:

- 1. Measured by voltage drop between A and B pins at the indicated current through the device. ON resistance is determined by the lower of the voltages on two ports (A or B).
- 2. Flatness is defined as difference between maximum and minimum value of ON resistance over the specified range of conditions. Guaranteed by design.

 $Capacitance^{(1)}$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
C_{IN}	Control Input		-	3.5	-	
C_{IO-B}	For B Port, Switch OFF	$V_{CC} = 5.0V, f = 1 \text{ MHz}, T_A = 25^{\circ}C$	-	15.0	-	рF
C_{IOA-ON}	For A Port, Switch ON	, , , , , , , , , , , , , , , , , , ,	-	34.0	-	1

Notes:

Switch and AC Characteristics (1)

Parameter	Description	Test Conditions	Supply Voltage	Min	Тур	Max	Units
	The control of the co	G F' 1	$V_{CC} = 2.7V \text{ to } 3.6V$	-	3	-	
t_{ON}	Turn on Time	See Figure 1	$V_{CC} = 4.5 V \text{ to } 5.5 V$	-	2	1	
t	Turn off Time	See Figure 1	$V_{CC} = 2.7V \text{ to } 3.6V$	-	9	-	ns
t_{OFF}	Turn on Time	See rigule 1	$V_{\rm CC} = 4.5 \text{V to } 5.5 \text{V}$	-	5	-	
		$C_L = 1nF, V_{GEN} = 0V,$	$V_{CC} = 5.0V$	-	35	1	
Q	Charge Injection	R_{GEN} = 0Ω . See Figure 2	$V_{CC} = 3.3V$	-	25	-	- pC
${ m O}_{ m IRR}$		R_L =50 Ω , V_{GEN} =0 V , R_{GEN} =0 Ω , f =1MHz. See Figure 3 (2)	V _{CC} =1.65V to 5.5V	-	-70	-	dB
f3dB	-3dB Bandwidth	See Figure 6	$V_{CC} = 1.65 \text{V} \text{ to } 5.5 \text{V}$	-	200	-	MHz
$T_{ m HD}$	Total Harmonic Distortion	$ m R_L$ =600 Ω , $ m V_{IN}$ =0.5 V pp, f=20 Hz to 20 k Hz See Figure 7	V _{CC} =2.7V to 4.2V	-	0.015	-	%

Notes:

- 1. Guaranteed by design.
- 2. Off Isolation = $20 \text{ Log}_{10}[V_B/V_A]$ and is measured in dB.

^{1.} Capacitance is characterized but not tested in production



Test Circuits and Timing Diagrams

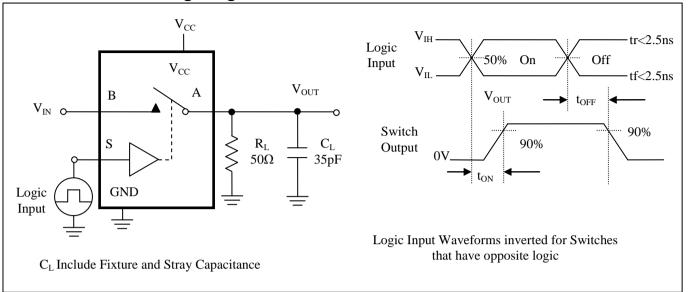


Figure 1. Turn ON/OFF Timing

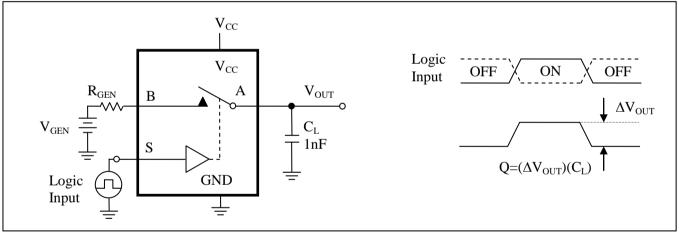


Figure 2. Charge Injection Test



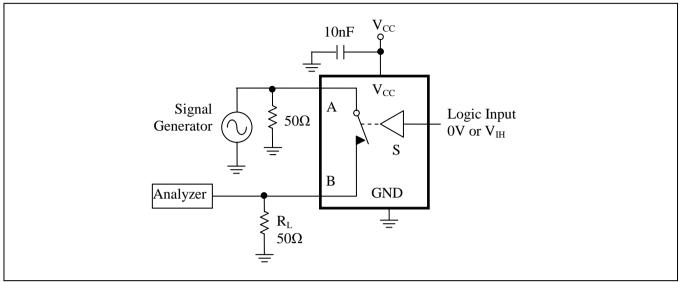


Figure 3. Off Isolation

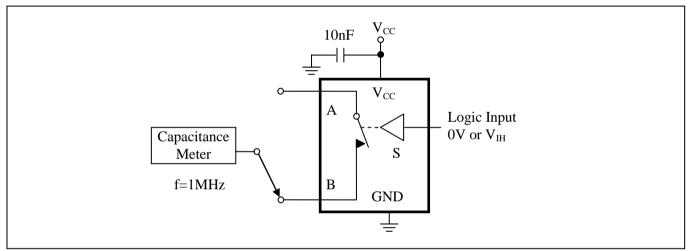


Figure 4. Channel Off Capacitance

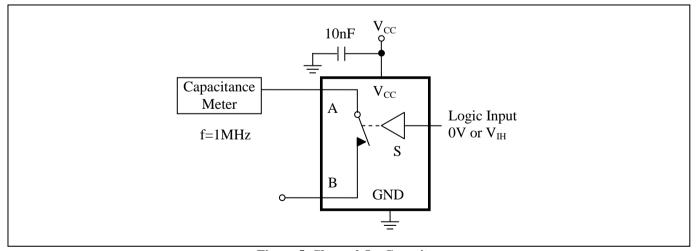


Figure 5. Channel On Capacitance





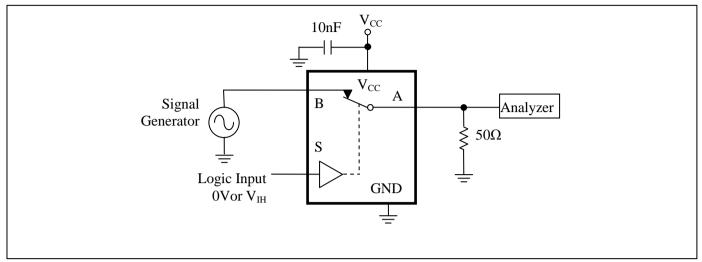


Figure 6. Bandwidth

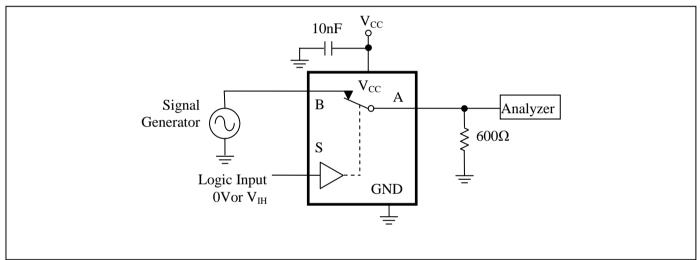


Figure 7. Harmonic Distortion

Part Marking

TA Package

pT: PI5A3166TAE



Y: Year

W: Workweek

Bar above "T" means Fab3 of MGN

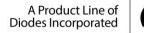
C Package



pT: Top Mark

XX: Date Code (Year & Work Week)
Bar above "T" means Fab3 of MGN

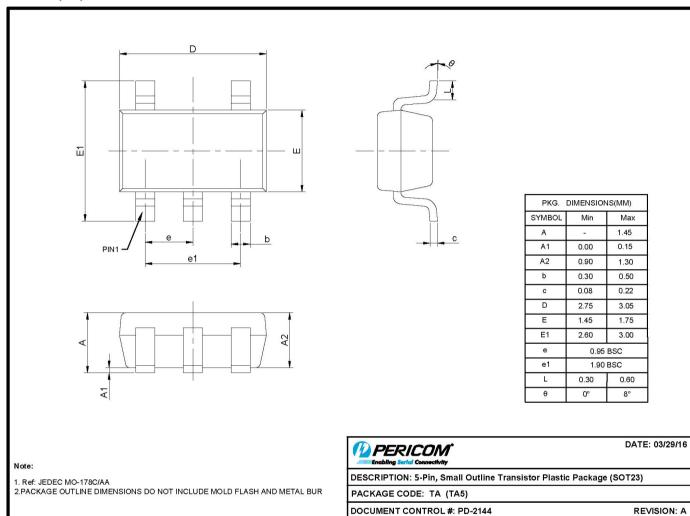






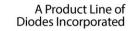
Packaging Mechanical

SOT23-5 (TA)



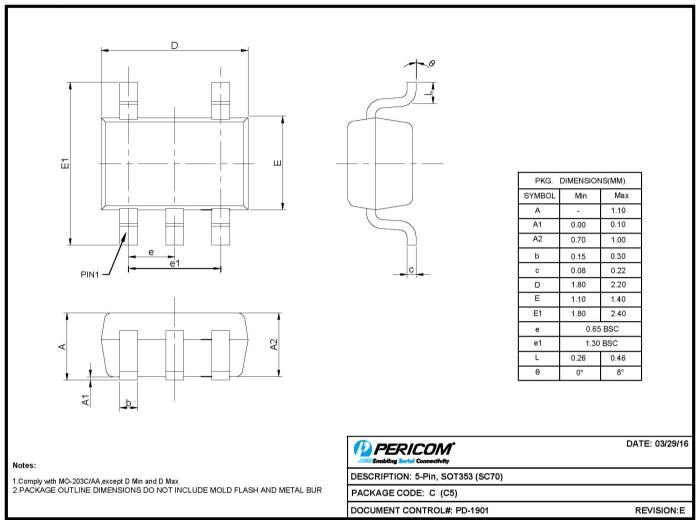
16-0081







SC70-5 (C)



16-0091

For latest package information:

Please see http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/.

Ordering Information

Part Number	Package Code	Description
PI5A3166CEX	С	5-Pin, SOT353 (SC70)
PI5A3166TAEX	TA	5-Pin, Small Outline Transistor Plastic Package (SOT23)

Notes:

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- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel





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